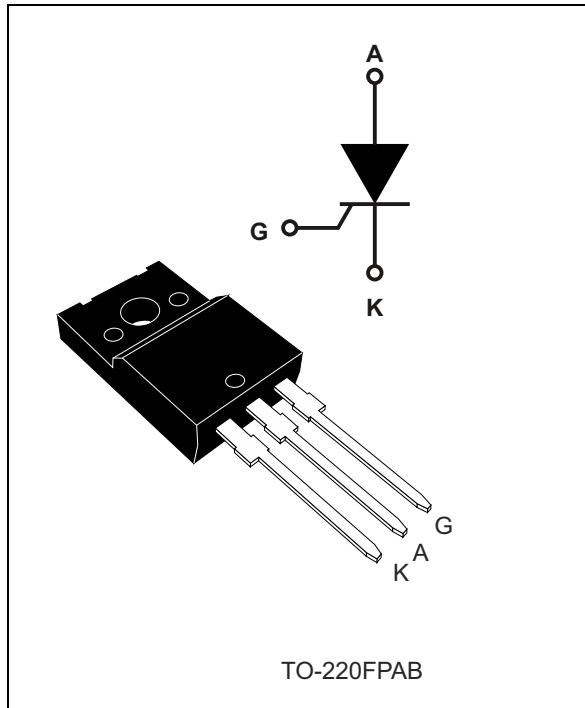


High temperature 16 A SCRs

Datasheet — production data



Features

- High junction temperature: $T_j = 150\text{ °C}$
- High noise immunity $dV/dt = 200\text{ V}/\mu\text{s}$ up to 150 °C
- Gate triggering current $I_{GT} = 6\text{ mA}$
- Blocking voltage $V_{DRM}/V_{RRM} = 600\text{ V}$
- High turn on current rise $dI/dt: 100\text{ A}/\mu\text{s}$
- ECOPACK[®]2 compliant component
- Complies with UL standards (File ref: E81734)
- Insulated package TO-220FPAB:
 - Insulated voltage: 2000 VRMS

Applications

- Voltage regulator circuits for motorbikes
- Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

Description

Thanks to a junction temperature up to 150 °C and an insulated TO-220FPAB package, the TN1605H-6FP offers high thermal performance up to 16 A rms.

The trade-off between the device's noise immunity ($dV/dt = 200\text{ V}/\mu\text{s}$), its gate triggering current ($I_{GT} = 6\text{ mA}$) and its turn-on current rise ($dI/dt = 100\text{ A}/\mu\text{s}$) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances, and inrush current limiting circuits.

The insulated fullpack package allows a back-to-back configuration.

Table 1. Device summary

Order code	Package	V_{DRM}/V_{RRM}	I_{GT}
TN1605H-6FP	TO-220FPAB	600 V	6 mA

1 Characteristics

Table 2. Absolute ratings

Symbol	Parameter			Value	Unit
I _{T(RMS)}	On-state rms current (180° conduction angle)		T _c = 83 °C	16	A
I _{T(AV)}	Average on-state current (180° conduction angle)		T _c = 83 °C	10	A
			T _c = 102 °C	8	
			T _c = 117 °C	6	
I _{TSM}	Non repetitive surge peak on-state current (T _j initial = 25 °C)		t = 8.3ms	153	A
			t = 10 ms	140	
I ² t	I ² t value for fusing (T _j initial = 25 °C)		t _p = 10 ms	98	A ² s
dI/dt	Critical rate of rise of on-state current I _G = 2 x I _{GT} , t _r ≤ 100 ns, T _j = 25 °C		f = 60 Hz	100	A/μs
V _{DRM} , V _{RRM}	Repetitive peak off-state voltage			600	V
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	A
P _{G(AV)}	Average gate power dissipation		T _j = 150 °C	1	W
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C
T _L	Maximum lead temperature for soldering during 10 s			260	°C
V _{ins}	Insulation rms voltage, 1 minute		TO-220FPAB	2000	V

Table 3. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Test conditions			Value	Unit
I_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$		Min.	3.5	mA
			Typ.	4.5	
			Max.	6	
V_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$		Max.	1.3	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	$T_j = 150\text{ °C}$	Min.	0.2	V
I_H	$I_T = 500\text{ mA}$, gate open		Max.	20	mA
I_L	$I_G = 1.2 \times I_{GT}$		Max.	40	mA
dV/dt	$V_D = 402\text{ V}$, gate open	$T_j = 150\text{ °C}$	Min.	200	V/ μ s
t_{gt}	$I_T = 32\text{ A}$, $V_D = 600\text{ V}$, $I_G = 100\text{ mA}$, (dI_G/dt)max = 0.2 A/ μ s		Typ	1.9	μ s
t_q	$V_D = 402\text{ V}$, $V_R = 25\text{ V}$, $I_T = 16\text{ A}$, (dI_G/dt)max = 30A/ μ s, $dV_D/dt = 40\text{ V}/\mu\text{s}$	$T_j = 150\text{ °C}$	Typ	70	μ s

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	$I_{TM} = 32 \text{ A}$, $t_p = 380 \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	1.6	V
V_{t0}	Threshold voltage	$T_j = 150 \text{ }^\circ\text{C}$	Max.	0.82	V
R_d	Dynamic resistance	$T_j = 150 \text{ }^\circ\text{C}$	Max.	25	m Ω
I_{DRM} , I_{RRM}	$V_D = V_{DRM}$, $V_R = V_{RRM}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	5	μA
		$T_j = 150 \text{ }^\circ\text{C}$		1.5	mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	4.5	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient (DC)	60	$^\circ\text{C/W}$

Figure 1. Maximum power dissipation versus average on-state current

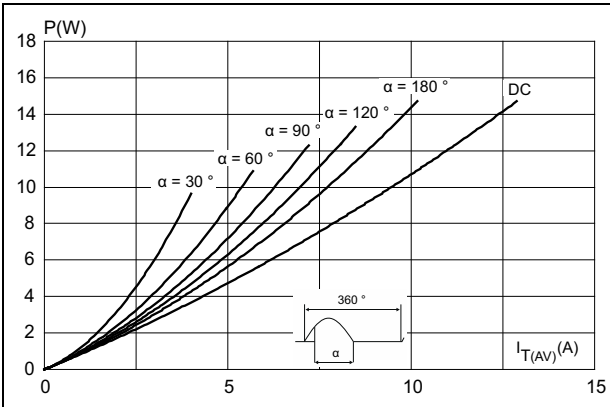


Figure 2. Average and DC on-state current versus case temperature

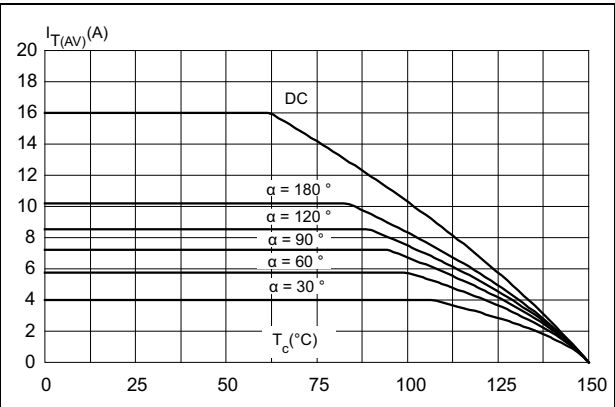


Figure 3. Average and DC on-state current versus ambient temperature

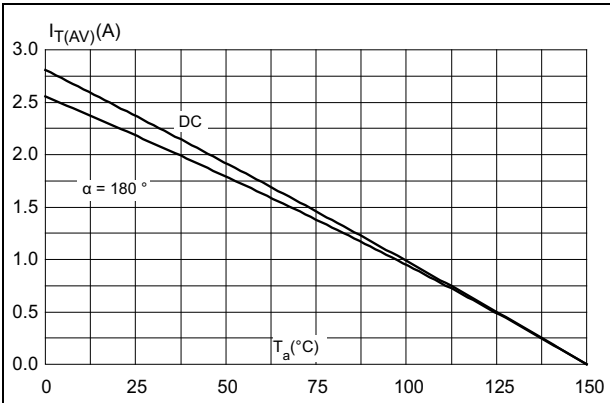


Figure 4. Relative variation of thermal impedance versus pulse duration

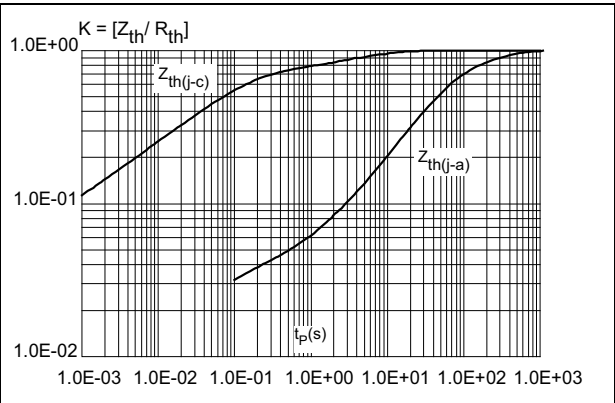


Figure 5. Relative variation of gate triggering current and gate voltage versus junction temperature (typical values)

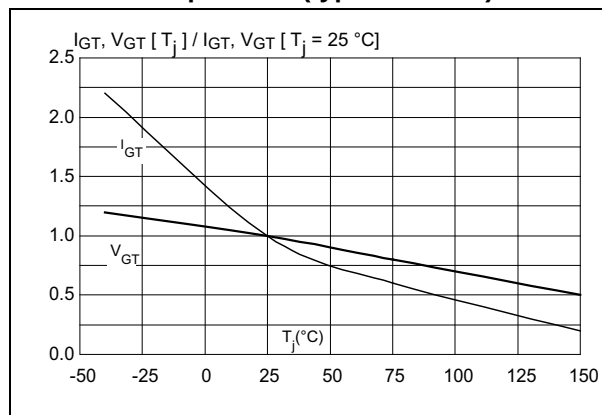


Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)

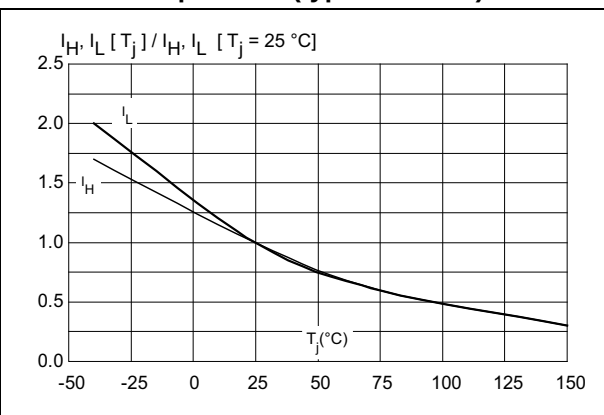


Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

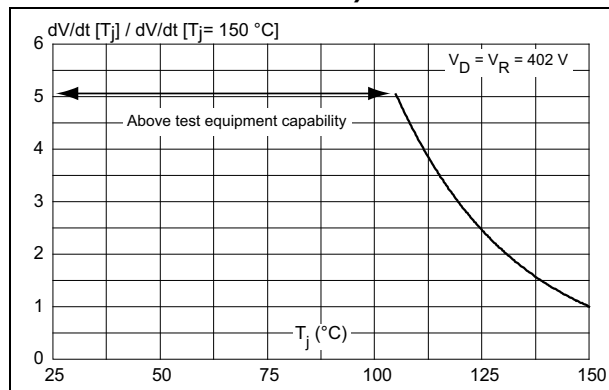


Figure 8. Surge peak on-state current versus number of cycles

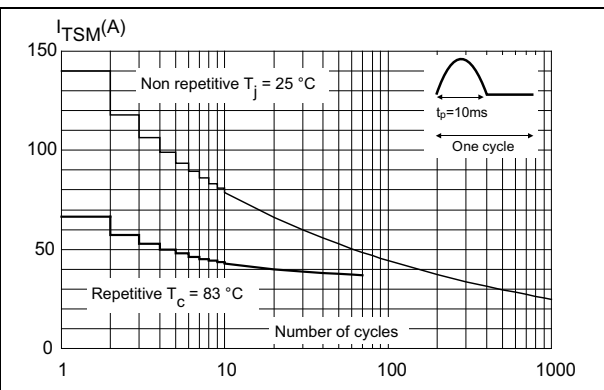


Figure 9. Non-repetitive surge peak on-state current for a sinusoidal pulse ($t_p < 10\text{ ms}$)

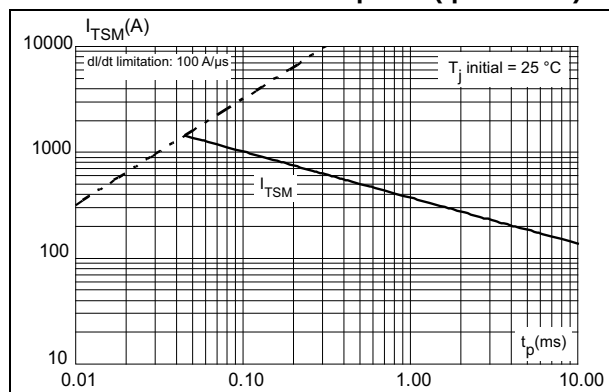


Figure 10. On-state characteristics (maximum values)

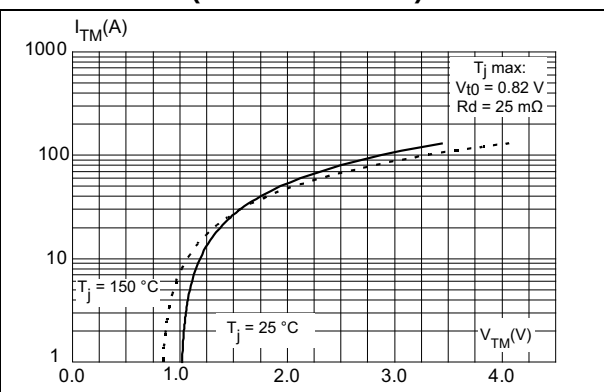
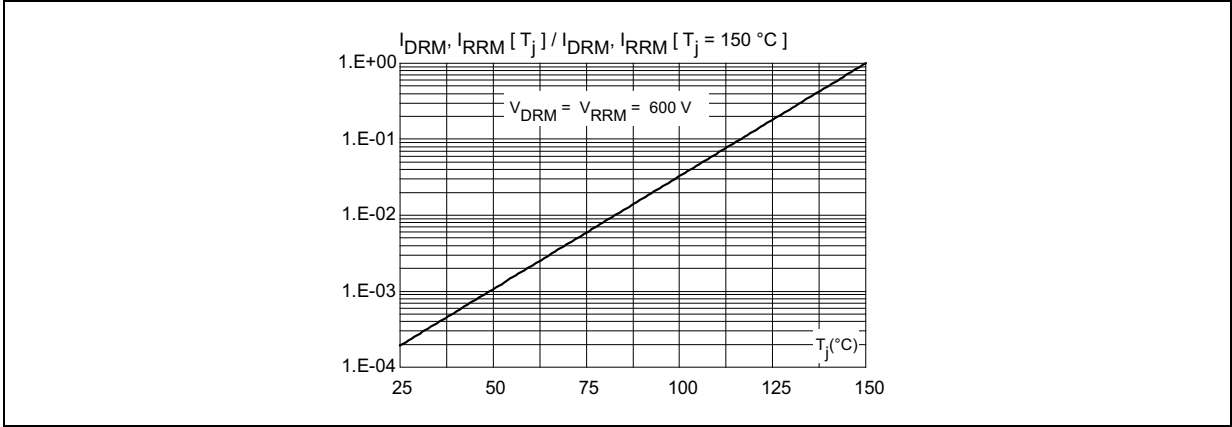


Figure 11. Relative variation of leakage current versus junction temperature (tp < 10 ms)



2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Halogen free molding compound
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Figure 12. TO-220FPAB dimension definitions

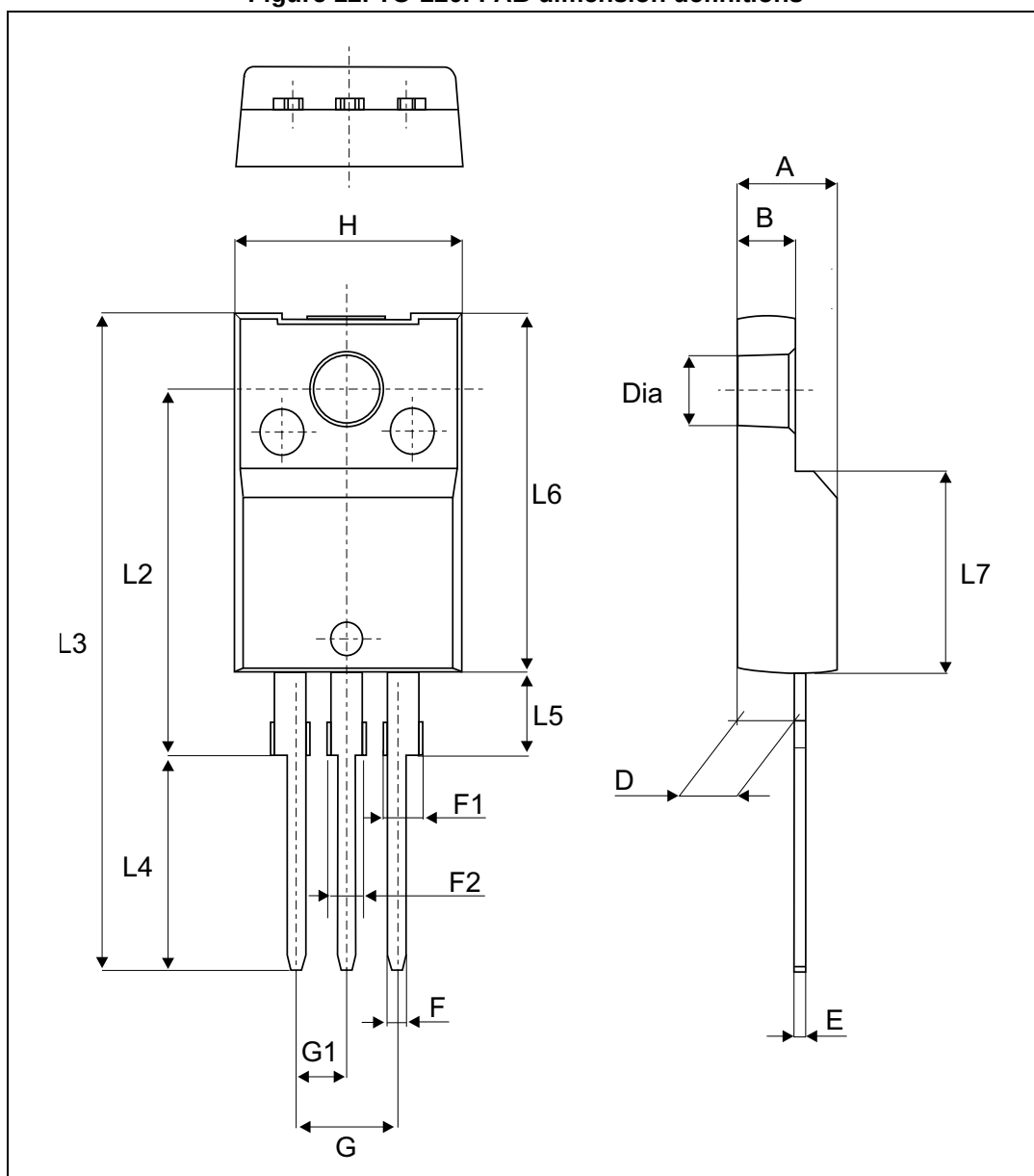


Table 6. TO-220FPAB dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

3 **Ordering information**

Figure 13. Ordering information scheme

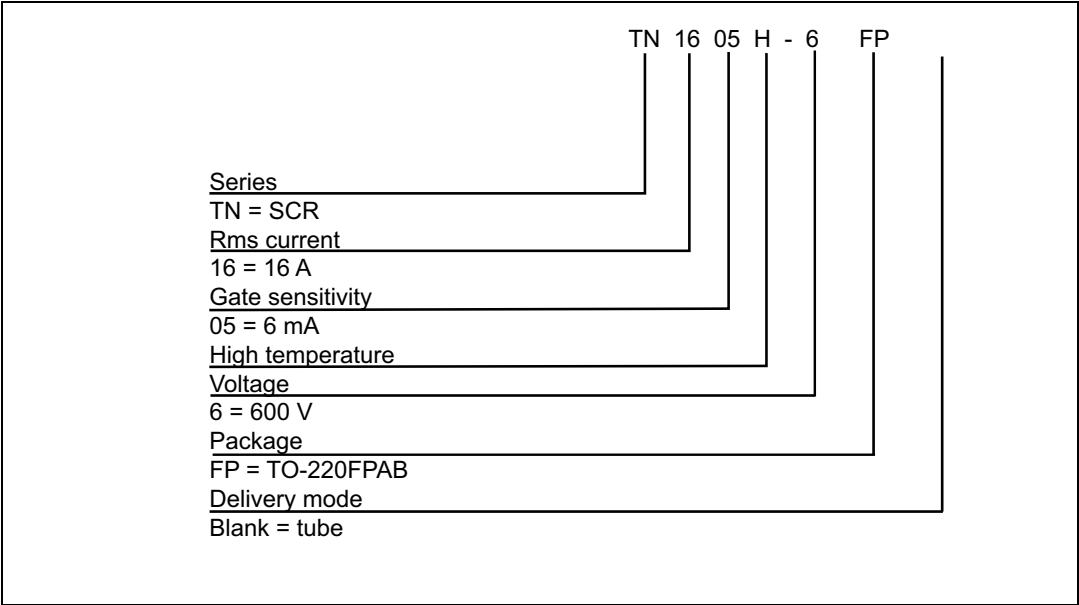


Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
TN1605H-6FP	TN1605H6	TO-220FPAB	2.0 g	50	Tube

4 **Revision history**

Table 8. Document revision history

Date	Revision	Changes
24-Feb-2015	1	Initial release.

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